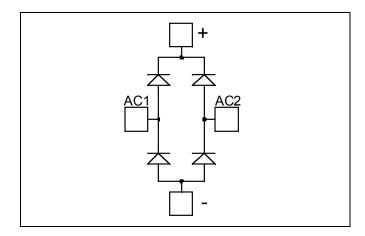


APTDF200H20

Fast Diode Rectifier Bridge Power Module

$$V_{RRM} = 200V$$

 $I_C = 200A$ @ $T_C = 80^{\circ}C$



AC1

Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance

Absolute maximum ratings

Symbol	Parameter				Max ratings	Unit	
V_R	Maximum DC reverse Voltage			200	V		
V_{RRM}	Maximum Peak Repetitive Reverse	Maximum Peak Repetitive Reverse Voltage				V	
I _{F(A V)}	Maximum Average Forward	Duty cycl	a = 500/ ₂	$T_C = 25^{\circ}C$	285		
	Current	Duty Cycl	C - 30 / 0	$T_C = 80$ °C	200	A	
I _{F(RMS)}	RMS Forward Current	Duty cycle = 50%		$T_C = 45^{\circ}C$	285		
I_{FSM}	Non-Repetitive Forward Surge Cu	rrent 8.3 ms		$T_C = 45^{\circ}C$	1500		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.



APTDF200H20

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{F}	Diode Forward Voltage	$I_F = 200A$			1.0	1.1	
		$I_F = 400 A$			1.4		V
		$I_F = 200A$	$T_{j} = 125^{\circ}C$		0.9		
I_{RM}	Maximum Reverse Leakage Current	$V_{\rm p} = 200 \text{V}$	$T_j = 25$ °C			350	^
			$T_{j} = 125^{\circ}C$			600	μΑ
C_{T}	Junction Capacitance	$V_R = 200 V$			800		pF

Dynamic Characteristics

•	Characteristic	Test Conditions		Min	Typ	Max	Unit
t _{rr}	Reverse Recovery Time	$I_F=1 A, V_R=30 V$ $di/dt = 200 A/\mu s$	$T_j = 25^{\circ}C$		39		ns
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		60		- ns
ЧT	Reverse Recovery Time		$T_j = 125^{\circ}C$		110		
Qn	Reverse Recovery Charge	$I_F = 200 A$ $V_R = 133 V$ $di/dt = 400 A/\mu s$	$T_j = 25^{\circ}C$		400		nC
Vп	Reverse Recovery Charge		$T_j = 125^{\circ}C$		1680		пс
I_{RRM}	Reverse Recovery Current		$T_j = 25^{\circ}C$		12		Α
1RRM	Reverse Recovery Current		$T_{j} = 125^{\circ}C$		30		
t_{rr}	Reverse Recovery Time	$I_F = 200 A$ $V_R = 133 V$ $di/dt = 2000 A/\mu s$			80		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 125$ °C		3.82		μС
I_{RRM}	Reverse Recovery Current				88		A

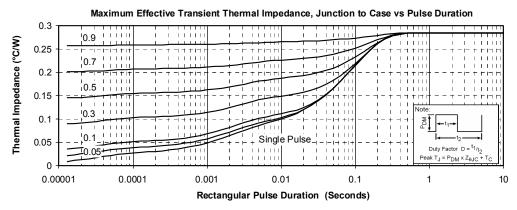
Thermal and package characteristics

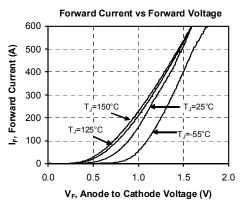
Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case					0.285	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, I isol<1mA, 50/60Hz			2500			V
T_{J}	Operating junction temperature range			-40		150	°C
T_{STG}	Storage Temperature Range			-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
	Woulding torque	For terminals	M5	2		3.5	14.111
Wt	Package Weight	·				280	g

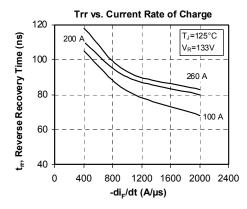


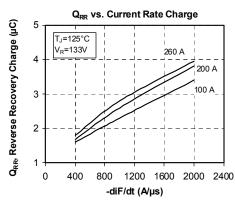


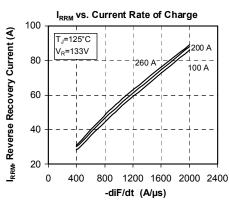
Typical Performance Curve

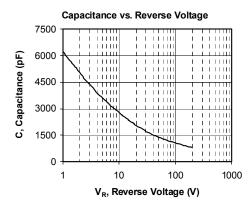


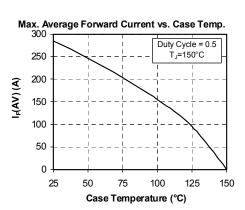








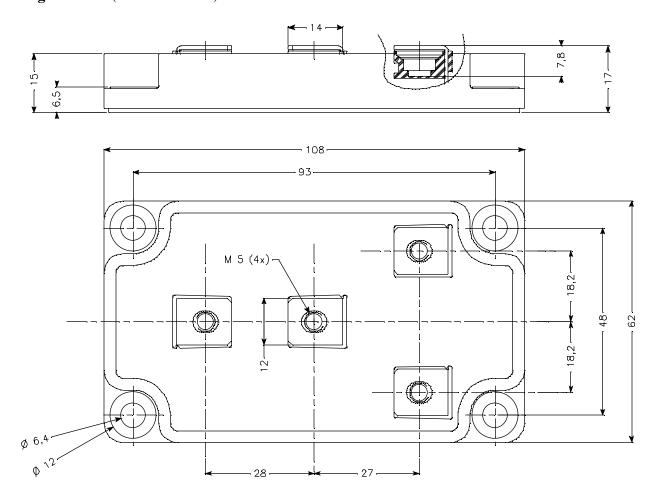








Package outline (dimensions in mm)



APT reserves the right to change, without notice, the specifications and information contained herein

APT's products are covered by one or more of U.S patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.